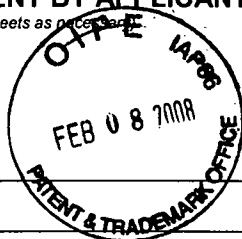


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Application Number	09/945,535
Filing Date	August 30, 2001
First Named Inventor	Ahn, Kie
Group Art Unit	2813
Examiner Name	Rodgers, Colleen

Sheet 1 of 4

Attorney Docket No: 1303.026US1

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<b>Examiner Name</b>	Rodgers, Colleen

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Attorney Docket No: 1303.026US1

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<b>First Named Inventor</b>	Ahn, Kie
<b>Group Art Unit</b>	2813
<b>Examiner Name</b>	Rodgers, Colleen

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